# **XBS306S17R-G**



ETR1616-002a

# Schottky Barrier Diode, 3A, 60V Type

#### **■**FEATURES

Forward Voltage : V<sub>F</sub>=0.59V (TYP.)

Forward Current :  $I_{F(AVE)}$ =3A Repetitive Peak Reverse Voltage :  $V_{RM}$ =60V

# **■**APPLICATIONS

- Rectification
- Protection against reverse connection of battery

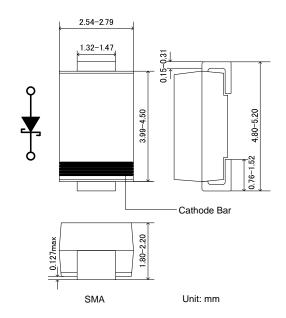
#### ■ABSOLUTE MAXIMUM RATINGS

Ta=25°C

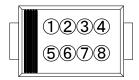
PARAMETER	SYMBOL	BOL RATINGS		
Repetitive Peak Reverse Voltage	Vrm	60	V	
Reverse Voltage (DC)	VR	60	V	
Forward Current (Average)	Current (Average) IF(AVE) 3		Α	
Non Continuous		50	Α	
Forward Surge Current <sup>*1</sup>	IFSM	50	A	
Junction Temperature	Tj	125	ပ္	
Storage Temperature Range	Tstg	-55 <b>~</b> +150	°C	

<sup>\*1:</sup> Non continuous high amplitude 60Hz half-sine wave.

# ■ PACKAGING INFORMATION



#### ■MARKING RULE



①23456: 306S17(Product Number)

: Assembly Lot Number

# **■PRODUCT NAME**

PRODUCT NAME	DEVICE ORIENTATION		
XBS306S17 R-G	SMA (Halogen & Antimony free)		
XBS306S17 R	SMA		

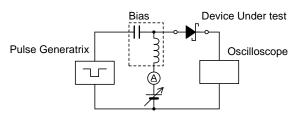
<sup>\*</sup> The "-G" suffix indicates that the products are Halogen and Antimony free as well as being fully RoHS compliant.

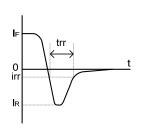
#### **■**ELECTRICAL CHARACTERISTICS

Ta=25°C

PARAMETER SYMBO	CVMPOL	TEST CONDITIONS	LIMITS			UNIT
	STIVIBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Forward Voltage VF1 VF2	VF1	I <sub>F</sub> =200 μ A	-	0.145	-	V
	VF2	I <sub>F</sub> =3A	-	0.59	0.66	V
Reverse Current IR1	l <sub>R1</sub>	V <sub>R</sub> =30V	-	3	=	μΑ
	lR2	V <sub>R</sub> =60V	-	9	300	μΑ
Inter-Terminal Capacity	Ct	V <sub>R</sub> =1V , f=1MHz	-	195	-	pF
Reverse Recovery Time*2	trr	I <sub>F</sub> =I <sub>R</sub> =10mA , irr=1mA	-	55	-	ns

<sup>\*2 :</sup> trr measurement circuit



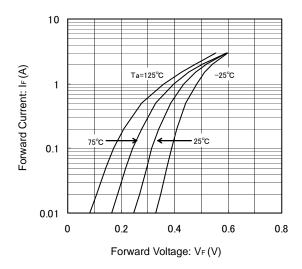


<sup>\*</sup> The device orientation is fixed in its embossed tape pocket.

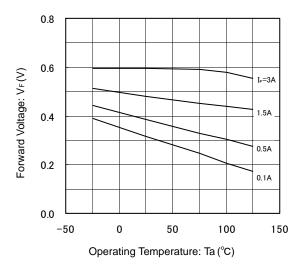
# XBS306S17R-G

#### **■**TYPICAL PERFORMANCE CHARACTERISTICS

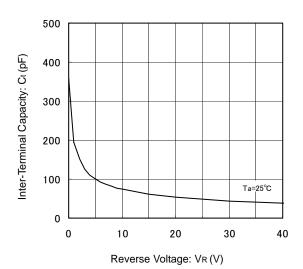
(1) Forward Current vs. Forward Voltage



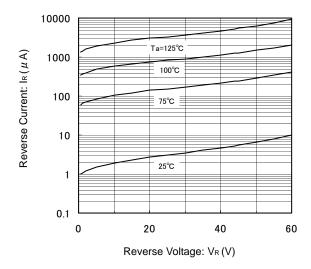
(3) Forward Voltage vs. Operating Temperature



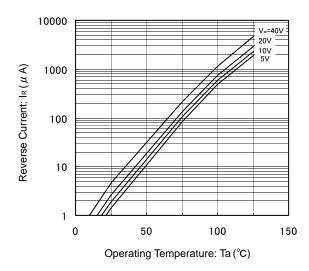
(5) Inter-Terminal Capacity vs. Reverse Voltage



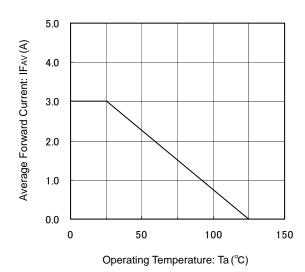
(2) Reverse Current vs. Reverse Voltage



(4) Reverse Current vs. Operating Temperature



(6) Average Forward Current vs. Operating Temperature



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